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Coherent Semiconductor Optics
This book covers the physics of semiconductors on an introductory level, assuming that the reader already has some knowledge of condensed matter physics. Crystal structure, band structure, carrier transport, phonons, scattering processes and optical properties are presented for typical semiconductors such as silicon, but III–V and II–VI compounds are also included. In view of the increasing importance of wide-gap semiconductors, the electronic and optical properties of these materials are dealt with too.

Isotope Low-Dimensional Structures

Optical Switching in Low-Dimensional Systems
The workshop on "Optical Properties of Low Dimensional Silicon Sl Structures" was held in Meylan, France on March 1, 1993. The workshop took place inside the facilities of France Telecom - CNET. Around 45 leading scientists working on this rapidly moving field were in attendance. Principal support was provided by the Advanced Research Workshop Program of the North Atlantic Treaty Organisation (NATO). French Delegation a l'Armement and CNET gave also a small financial grant, the organisational part being undertaken by the SEE and CNET. There is currently intense research activity worldwide devoted to the optical properties of low dimensional silicon structures. This follow the recent discovery of efficient visible photoluminescence (PL) from highly porous silicon. This workshop was intended to bring together all the leading European scientists and laboratories in order to reveal the state of the art and to open new research fields on this subject. A large number of invited talks took place (12) together with regular contribution (20). The speakers were asked to leave nearly 1/3 of the time to the discussion with the audience, and that promoted both formal and informal discussions between the participants.

Two-Dimensional Coulomb Liquids and Solids
This report presents an account of the course "Nonlinear Spectroscopy of Solids: Advances and Applications" held in Erice, Italy, from June 16 to 30, 1993. This meeting was organized by the International School of Atomic and Molecular Spectroscopy of the "Ettore Majorana" Centre for Scientific Culture. The purpose of this course was to present and discuss physical models, mathematical formalisms, experimental techniques, and applications relevant to the subject of nonlinear spectroscopy of solid state materials. The universal availability and application of lasers in spectroscopy has led to the widespread observation of nonlinear effects in the spectroscopy of materials. Nonlinear spectroscopy encompasses many physical phenomena which have their origin in the monochromaticity, spectral brightness, coherence, power density and tunability of laser sources. Conventional spectroscopy assumes a linear dependence between the applied electromagnetic field and the induced polarization of atoms and molecules. The validity of this assumption rests on the fact that even the most powerful conventional sources of light produce a light intensity which is not strong enough to equalize the rate of stimulated emission and that of the experimentally observed decay. A different situation may arise when laser light sources are used, particularly pulsed lasers. The use of such light sources can make the probability of induced emission comparable to, or even greater than, the probability of the observed decay; in such cases the nonlinearity of the response of the system is revealed by the experimental data and new properties, not detectable by conventional spectroscopy, will emerge.
Electronic States in Crystals of Finite Size The book describes how the electrons in small "low-dimensional" structures interact with their surroundings. It contains a series of linked up to date review chapters as well as explanatory material and is written to be understandable to graduate students and newcomers to the field. All contributions come from leading scientists.

Exciton Dynamics in Lead Halide Perovskite Nanocrystals This Advanced Study Institute on the Electronic Properties of Multilayers and Low Dimensional Semiconductor Structures focussed on several of the most active areas in modern semiconductor physics. These included resonant tunnelling and superlattice phenomena and the topics of ballistic transport, quantised conductance and anomalous magnetoresistance effects in laterally gated two-dimensional electron systems. Although the main emphasis was on fundamental physics, a series of supporting lectures described the underlying technology (Molecular Beam Epitaxy, Metallo-Organic Chemical Vapour Deposition, Electron Beam Lithography and other advanced processing technologies). Actual and potential applications of low dimensional structures in optoelectronic and high frequency devices were also discussed. The ASI took the form of a series of lectures of about fifty minutes' duration which were given by senior researchers from a wide range of countries. Most of the lectures are recorded in these Proceedings. The younger members of the Institute made the predominant contribution to the discussion sessions following each lecture and, in addition, provided most of the fifty-five papers that were presented in two lively poster sessions. The ASI emphasised the impressive way in which this research field has developed through the fruitful interaction of theory, experiment and semiconductor device technology. Many of the talks demonstrated both the effectiveness and limitations of semiclassical concepts in describing the quantum phenomena exhibited by electrons in low dimensional structures.

Confined Electrons and Photons Gives a comprehensive and coherent account of the basic methods to characterize a solid through its interaction with an electromagnetic field.

Science and Engineering of One- and Zero-Dimensional Semiconductors This text is a first attempt to pull together the whole of semiconductor science and technology since 1970 in so far as semiconductor multilayers are concerned. Material, technology, physics and device issues are described with approximately equal emphasis, and form a single coherent point of view. The subject matter is the concern of over half of today's active semiconductor scientists and technologists, the remainder working on bulk semiconductors and devices. It is now routine to design and the prepare semiconductor multilayers at a time, with independent control over the dropping and composition in each layer. In turn these multilayers can be patterned with features that as a small as a few atomic layers in lateral extent. The resulting structures open up many new areas of exciting solid state and quantum physics. They have also led to whole new generations of electronic and optoelectronic devices whose superior performance relates back to the multilayer structures. The principles established in the field have several decades to go, advancing towards the ultimate of materials engineering, the design and preparation of solids atom by atom. The book should appeal equally to physicists, electronic engineers and materials scientists.

Electronic Excitations in Organic Based Nanostructures The author develops the effective-mass theory of excitons in low-dimensional semiconductors and describes numerical methods for calculating the optical absorption including Coulomb interaction, geometry, and external fields. The theory is applied to Fano resonances in low-dimensional semiconductors and the Zener breakdown in superlattices. Comparing theoretical results with experiments, the book is essentially self-contained; it is a hands-on approach with detailed derivations, worked examples, illustrative figures, and computer programs. The book is clearly structured and will be valuable as an advanced-level self-study or course book for graduate students, lecturers, and researchers.

Physics of Semiconductors and Nanostructures This volume investigates the theory of the effect of static electric fields on one-electron states in nanocylindrical and nanospherical heterolayers and quantized semiconductor films. Homogeneous external electrostatic field for all these structures has been considered as a "universal" modulating factor. For structures with radial symmetry, a study on the influence of radial static field and the electric field of a charged ring on one-electron states is presented. Chapters focusing on homogeneous field effect on low-dimensional excitonic states in the quantized films and quantum wires - in both wide bandgap and narrowband semiconductors - are also included. Other contents include calculations weak, moderate and strong electric fields, quantum-mechanical approximation and perturbation theory, the quasi-classical approximation (WKB method). Readers will benefit from the varied methodological to the subject which gives them a concrete analytical framework to solve problems related to nanoscale semiconductor design. The reference should prove to be useful to academics and professionals working in semiconductor nanoelectronics research and development.

Many-Body Approach to Electronic Excitations This book, Condensed Matter and Material Physics, incorporates the work of multiple authors to enhance the theoretical as well as experimental knowledge of materials. The investigation of crystalline solids is a growing need in the electronics industry. Micro and nano transistors require an in-depth understanding of semiconductors of different groups. Amorphous materials, on the other hand, as non-equilibrium materials are widely applied in sensors and other medical and industrial applications. Superconducting magnets, composite materials, lasers, and many more applications are integral parts of our daily lives. Superfluids, liquid crystals, and polymers are undergoing active research throughout the world. Hence profound information on the nature and application of various materials is in demand. This book bestows on the reader a deep knowledge of physics behind the concepts, perspectives, characteristic properties, and prospects. The book was constructed using 10 contributions from experts in diversified fields of
condensed matter and material physics and its technology from over 15 research institutes across the globe.

Low-dimensional Nitride Semiconductors Recent years have witnessed the discovery of many striking new aspects of the optical response and electronic transport phenomena. This book surveys this progress in the physics, optical spectroscopy and application-oriented research of semiconductor quantum dots. It focuses especially on excitons, multi-excitons, their dynamical relaxation behaviour and their interactions with the surroundings of a semiconductor quantum dot. Recent developments in fabrication techniques are reviewed and potential applications discussed. This book will serve not only as an introductory textbook for graduate students but also as a concise guide for active researchers.

Proceedings of the Fifth International Symposium on Quantum Confinement, Nanostructures This invaluable textbook presents the basic elements needed to understand and research into semiconductor physics. It deals with elementary excitations in bulk and low-dimensional semiconductors, including quantum wells, quantum wires and quantum dots. The basic principles underlying optical nonlinearities are developed, including excitonic and many-body plasma effects. Fundamentals of optical bistability, semiconductor lasers, femtosecond excitation, the optical Stark effect, the semiconductor photon echo, magneto-optic effects, as well as bulk and quantum-confined Franz-Keldysh effects, are covered. The material is presented in sufficient detail for graduate students and researchers with a general background in quantum mechanics.

Nonlinear Spectroscopy of Solids A recent major development in high technology, and one which bears considerable industrial potential, is the advent of low-dimensional semiconductor quantum structures. The research and development activity in this field is moving fast and it is thus important to afford scientists and engineers the opportunity to get updated by the best experts in the field. The present book draws together the latest developments in the field of nonlinear optical phenomena. It covers the basic physics of nonlinear phenomena, materials, and device structures, and provides an up-to-date, competent and extensive review of their fundamental properties and some remarkable applications. The book is based on a set of lectures that introduce different aspects of the basic knowledge available, it has a tutorial content and could be used as a textbook. Each aspect is reviewed, from elementary concepts up to the latest developments. Audience: Undergraduates and graduates in electrical engineering and physics schools. Also for active scientists and engineers, updating their knowledge and understanding of the frontiers of the technology.

Quantum Theory of the Optical and Electronic Properties of Semiconductors This book introduces the basic theoretical concepts required for the analysis of the optical response of semiconductor systems in the coherent regime. It is the most instructive textbook on the theory and optical effects of semiconductors. The entire presentation is based on a one-dimensional tight-binding model. Starting with discrete-level systems, increasing complexity is added gradually to the model by including band-structure and many-particle interaction. Various linear and nonlinear optical spectra and temporal phenomena are studied. The analysis of many-body effects in nonlinear optical phenomena covers a major part of the book.

Proceedings of the Third International Conference on Excitonic Processes in Condensed Matter, EXCON '98 This book fills a gap between many of the basic solid state physics and materials science textbooks that are currently available. It is written for a mixed audience of electrical engineering and applied physics students who have some knowledge of elementary undergraduate quantum mechanics and statistical mechanics. This book, based on a successful course taught at MIT, is divided pedagogically into three parts: (I) Electronic Structure, (II) Transport Properties, and (III) Optical Properties. Each topic is explained in the context of bulk materials and then extended to low-dimensional materials where applicable. Problem sets review the content of each chapter to help students to understand the material described in each of the chapters more deeply and to prepare them to master the next chapters.

Recent developments in fabrication techniques are reviewed and potential applications discussed. This book will serve not only as an introductory textbook for graduate students but also as a concise guide for active researchers.

Electronic Properties of Multilayers and Low-Dimensional Semiconductor Structures This volume contains the Proceedings of the NATO Advanced Research Workshop on "Growth and Optical Properties of Wide Gap II-VI Low Dimensional Semiconductors", held from 2 - 6 August 1988 in Regensburg, Federal Republic of Germany, under the auspices of the NATO International Scientific Exchange Programme. Semiconducting compounds formed by combining an element from column II of the periodic table with an element from column VI of the periodic table have long promised many optoelectronic devices operating in the visible region of the spectrum. However, these materials have encountered numerous problems including: large number of defects and difficulties in obtaining p- and n-type doping. Advances in new methods of material preparation may hold the key to unlocking the unfulfilled promises. During the workshop a full session was taken up covering the prospects for wide-gap II-VI semiconductor devices, particularly light emitting ones. The growth of bulk materials
was reviewed with the view of considering II-VI substrates for the novel epitaxial techniques such as MOCVD, MBE, ALE, MOMB, and ALE-MBE. The controlled introduction of impurities during nonequilibrium growth to provide control of the doping type and conductivity was emphasized.

Devices Based on Low-Dimensional Semiconductor Structures

Low-Dimensional Molecular Metals The first book devoted to a systematic consideration of electronic excitations and electronic energy transfer in organic crystalline multilayers and organics based nanostructures (quantum wells, quantum wires, quantum dots, microcavities). The ingenious combination of organic with inorganic materials in one and the same hybrid structure is shown to give qualitatively new opto-electronic phenomena, potentially important for applications in nonlinear optics, light emitting devices, photovoltaic cells, lasers and so on. The book will be useful not only for physicists but also for chemists and biologists. To help the non-specialist reader, three Chapters which contain a tutorial and updated introduction to the physics of electronic excitations in organic and inorganic solids have been included. * Hybrid Frenkel-Wannier-Mott excitons * microcavities with crystalline and disordered organics * electronic excitation at donor-acceptor interfaces * cold photoconductivity at donor-acceptor interface * cumulative photovoltage * Föster transfer energy in microcavity * New concepts for LEDs

Fabrication, Properties and Applications of Low-Dimensional Semiconductors Beginning graduate introduction to low-dimensional systems and their applications.

Effect of Static Electric Fields on The Electronic And Optical Properties of Layered Semiconductor Nanostructures Low-dimensional semiconductor quantum structures are a major, high-technological development that has a considerable industrial potential. The field is developing extremely rapidly and the present book presents a timely guide to the latest developments in device technology, fundamental properties, and some remarkable applications. The content is largely tutorial, and the book could be used as a textbook. The book deals with the physics, fabrication, characteristics and performance of devices based on low-dimensional semiconductor structures. It opens with fabrication procedures. The fundamentals of quantum structures and electro-optical devices are dealt with extensively. Nonlinear optical devices are discussed from the point of view of physics and applications of exciton saturation in MQW structures. Waveguide-based devices are also described in terms of linear and nonlinear coupling. The basics of pseudomorphic HEMT technology, device physics and materials layer design are presented. Each aspect is reviewed from the elementary basics up to the latest developments. Audience: Undergraduates in electrical engineering, graduates in physics and engineering schools. Useful for active scientists and engineers wishing to update their knowledge and understanding of recent developments.

Growth and Optical Properties of Wide-Gap II–VI Low-Dimensional Semiconductors This book is a comprehensive text on the physics of semiconductors and nanostructures for a large spectrum of students at the final undergraduate level studying physics, material science and electronics engineering. It offers introductory and advanced courses on solid state and semiconductor physics on one hand and the physics of low dimensional semiconductor structures on the other in a single text book. Key Features Presents basic concepts of quantum theory, solid state physics, semiconductors, and quantum nanostructures such as quantum well, quantum wire, quantum dot and superlattice In depth description of semiconductor heterojunctions, lattice strain and modulation doping technique Covers transport in nanostructures under an electric and magnetic field with the topics: quantized conductance, Coulomb blockade, and integer and fractional quantum Hall effect Presents the optical processes in nanostructures under a magnetic field Includes illustrative problems with hints for solutions in each chapter Physics of Semiconductors and Nanostructures will be helpful to students initiating PhD work in the field of semiconductor nanostructures and devices. It follows a unique tutorial approach meeting the requirements of students who find learning the concepts difficult and want to study from a physical perspective.

Nonlinear Optics and Optical Computing The many-body-theoretical basis and applications of theoretical spectroscopy of condensed matter, e.g. crystals, nanosystems, and molecules are unified in one advanced text for readers from graduate students to active researchers in the field. The theory is developed from first principles including fully the electron-electron interaction and spin interactions. It is based on the many-body perturbation theory, a quantum-field-theoretical description, and Green’s functions. The important expressions for ground states as well as electronic single-particle and pair excitations are explained. Based on single-particle and two-particle Green’s functions, the Dyson and Bethe-Salpeter equations are derived. They are applied to calculate spectral and response functions. Important spectra are those which can be measured using photoemission/inverse photoemission, optical spectroscopy, and electron energy loss/inelastic X-ray spectroscopy. Important approximations are derived and discussed in the light of selected computational and experimental results. Some numerical implementations available in well-known computer codes are critically discussed. The book is divided into four parts: (i) In the first part the many-electron systems are described in the framework of the quantum-field theory. The electron spin and the spin-orbit interaction are taken into account. Sum rules are derived. (ii) The second part is mainly related to the ground state of electronic systems. The total energy is treated within the density functional theory. The most important approximations for exchange and correlation are detailed. (iii) The third part is essentially devoted to the description of charged electronic excitations such as electrons and holes. Central approximations as Hedin’s GW and the
T-matrix approximation are discussed. (iv) The fourth part is focused on response functions measured in optical and loss spectroscopies and neutral pair or collective excitations.

Low-dimensional Semiconductors This coherent monograph describes and explains quantum phenomena in two-dimensional (2D) electron systems with extremely strong internal interactions, which cannot be described by the conventional Fermi-liquid approach. The central physical objects considered are the 2D Coulomb liquid, of which the average Coulomb interaction energy per electron is much higher than the mean kinetic energy, and the Wigner solid. The text provides a new and comprehensive review of the remarkable properties of Coulomb liquids and solids formed on the free surface of liquid helium and other interfaces. This book is intended for graduate students and researchers in the fields of quantum liquids, electronic properties of 2D systems, and solid-state physics. It includes different levels of sophistication so as to be useful for both theorists and experimentalists. The presentation is largely self-contained, and also describes some instructive examples that will be of general interest to solid-state physicists.

The Physics of Low-dimensional Semiconductors The composition of modern semiconductor heterostructures can be controlled precisely on the atomic scale to create low-dimensional systems. These systems have revolutionised semiconductor physics, and their impact on technology, particularly for semiconductor lasers and ultrafast transistors, is widespread and burgeoning. This book provides an introduction to the general principles that underlie low-dimensional semiconductors. As far as possible, simple physical explanations are used, with reference to examples from actual devices. The author shows how, beginning with fundamental results from quantum mechanics and solid-state physics, a formalism can be developed that describes the properties of low-dimensional semiconductor systems. Among numerous examples, two key systems are studied in detail: the two-dimensional electron gas, employed in field-effect transistors, and the quantum well, whose optical properties find application in lasers and other opto-electronic devices. The book includes many exercises and will be invaluable to undergraduate and first-year graduate physics or electrical engineering students taking courses in low-dimensional systems or heterostructure device physics.

Quantum Theory of the Optical and Electronic Properties of Semiconductors Optical Spectroscopy of Low Dimensional Semiconductors covers basic physical aspects, novel technology and material fabrication tools, characterization methods and new devices, with special emphasis on quantum wire and quantum dot lasers. Recent advances in special epitaxial growth techniques, especially on patterned substrates, are remarkable, allowing the fabrication of well-defined one- and zero-dimensional semiconductor systems. In addition to self-ordered quantum dots in a variety of materials other major topics include V-groove quantum wires, cleaved edge overgrowth, micro-cavities, electronic excitations in low dimensional systems, phonons and dissipative transport in nanostructures. Most of the papers cover III-V semiconductors, but Group IV and II-VI semiconductor microstructures are also covered. Theoretical papers are included on growth kinetics and the electronic properties of low dimensional structures, including many-particle effects.

The Physics of Low-dimensional Semiconductors This revised and updated edition of the well-received book by C. Klingshirn provides an introduction to and an overview of all aspects of semiconductor optics, from IR to visible and UV. It has been split into two volumes and rearranged to offer a clearer structure of the course content. Inserts on important experimental techniques as well as sections on topical research have been added to support research-oriented teaching and learning. Volume I provides an introduction to the linear optical properties of semiconductors. The mathematical treatment has been kept as elementary as possible to allow an intuitive approach to the understanding of results of semiconductor spectroscopy. Building on the phenomenological model of the Lorentz oscillator, the book describes the interaction of light with fundamental optical excitations in semiconductors (phonons, free carriers, excitons). It also offers a broad review of seminal research results augmented by concise descriptions of the relevant experimental techniques, e.g., Fourier transform IR spectroscopy, ellipsometry, modulation spectroscopy and spatially resolved methods, to name a few. Further, it picks up on hot topics in current research, like quantum structures, mono-layer semiconductors or Perovskites. The experimental aspects of semiconductor optics are complemented by an in-depth discussion of group theory in solid-state optics. Covering subjects ranging from physics to materials science and optoelectronics, this book provides a lively and comprehensive introduction to semiconductor optics. With over 120 problems, more than 480 figures, abstracts to each chapter, as well as boxed inserts and a detailed index, it is intended for use in graduate courses in physics and neighboring sciences like material science and electrical engineering. It is also a valuable reference resource for doctoral and advanced researchers.

Optical Characterization of Solids This monograph is concerned with the III-V bulk and low-dimensional semiconductors, with the emphasis on the implications of multi-valley bandstructures for the physical mechanisms essential for opto-electronic devices. The optical response of such semiconductor materials is determined by many-body effects such as screening, gap narrowing, Fermi-edge singularity, electron-hole plasma and liquid formation. Consequently, the discussion of these features reflects such interdependencies with the dynamics of excitons and carriers resulting from intervalley coupling.

Electron-phonon Interactions in Low-dimensional Structures Less than a decade ago, lead halide perovskite semiconductors caused a sensation: Solar cells exhibiting astonishingly high levels of efficiency. Recently, it became possible to synthesize nanocrystals of this material as well. Interestingly; simply
by controlling the size and shape of these crystals, new aspects of this material literally came to light. These nanocrystals have proven to be interesting candidates for light emission. In this thesis, the recombination, dephasing and diffusion of excitons in perovskite nanocrystals is investigated using time-resolved spectroscopy. All these dynamic processes have a direct impact on the light-emitting device performance from a technology point of view. However, most importantly, the insights gained from the measurements allowed the author to modify the nanocrystals such that they emitted with an unprecedented quantum yield in the blue spectral range. Resulting in the successful implementation of this material as the active layer in an LED. This represents a technological breakthrough, because efficient perovskite light emitters in this wavelength range did not exist before.

Excitons in Low-Dimensional Semiconductors This monograph assimilates new research in the field of low-dimensional metals. It provides a detailed overview of the current status of research on quasi-one- and two-dimensional molecular metals, describing normal-state properties, magnetic field effects, superconductivity, and the phenomena of interacting p and d electrons. It includes a number of findings likely to become standard material in future textbooks on solid-state physics.

Introduction to Semiconductor Physics The optical properties of semiconductors have played an important role since the identification of semiconductors as "small" bandgap materials in the thirties, due both to their fundamental interest as a class of solids having specific optical properties and to their many important applications. On the former aspect, we can cite the fundamental edge absorption and its assignment to direct or indirect transitions, many-body effects as revealed by exciton formation and photoconductivity. On the latter aspect, large-scale applications such as LEDs and lasers, photovoltaic converters, photodetectors, and low-dimensional electronic devices, come to mind. From the eighties a revivalization of the whole field due to the advent of heterostructures of lower-dimensionality, mainly two-dimensional quantum wells, which through their enhanced photon-matter interaction yielded new devices with unsurpassed performance. Although many of the basic phenomena were evidenced through the seventies, it was this impact on applications in turn led to such a massive investment in fabrication tools, thanks to which many new structures and materials were studied, yielding further advances in fundamental physics.

Optical Spectroscopy of Low Dimensional Semiconductors The conference "Nonlinear Optics and Optical Computing" was held May 11-19, 1988 in Erice, Sicily. This was the 13th conference organized by the International School of Quantum Electronics, under the auspices of the "Ettore Majorana" Center for Scientific Culture. This volume contains both the invited and contributed papers presented at the conference, providing tutorial background, the latest research results, and future directions for the devices, structures and architectures of optical computing. The invention of the transistor and the integrated circuit were followed by an explosion of application as ever faster and more complex microelectronics chips became available. The information revolution occasioned by digital computers and optical communications is now reaching the limits of silicon semiconductor technology, but the demand for faster computation is still accelerating. The fundamental limitations of information processing today derive from the performance and cost of three technical factors: speed, density, and software. Optical computation offers the potential for improvements in all three of these critical areas: speed is provided by the transmission of impulses at optical velocities, without the delays caused by parasitic capacitance in the case of conventional electrical interconnects. Speed can also be achieved through the massive parallelism characteristic of many optical computing architectures; Density can be provided in optical computers in two ways: by high spatial resolution, on the order of wavelengths of light, and by computation or interconnection in three dimensions.

Optical Properties of Low Dimensional Silicon Structures Optoelectronics and electronics of the years to come are likely to change dramatically. Most of the outdoor lighting systems will be replaced by light-emitting diodes that operate in the whole visible part of the electromagnetic spectrum. Transistors operating at high frequency and with high power are under development and likely to hit the market very rapidly. Compact solid-state lasers that operate in the near-ultraviolet range are going to be utilized for such widely used applications as read-write tasks in printer and CD drives. Ultraviolet detectors will be used at a wide scale for many application, ranging from flame detectors to medical instruments. This book concerns itself with the questions why nitride semiconductors are so promising over such a wide range of applications, what the current issues are in the research laboratories, and what the prospects of new electronic devices are in the dawn of the twenty-first century.

Photo-Excited Processes, Diagnostics and Applications This book contains all the papers presented at the NATO workshop on "Optical Switching in Low Dimensional Systems" held in Marbella, Spain from October 6th to 8th, 1988. Optical switching is a basic function for optical data processing, which is of technological interest because of its potential parallelism and its potential speed. Semiconductors which exhibit resonance enhanced optical nonlinearities in the frequency range close to the band edge are the most intensively studied materials for optical bistability and fast gate operation. Modern crystal growth techniques, particularly molecular beam epitaxy, allow the manufacture of semiconductor microstructures such as quantum wells, quantum wires and quantum dots in which the electrons are only free to move in two, one or zero dimensions, of the optically excited electron-hole pairs in these low dimensional structures. The spatial confinement dimensional structures gives rise to an enhancement of the excitonic nonlinearities. Furthermore, the variations of the microstructure extensions, of the compositions, and of the doping offers great new flexibility in engineering the desired optical properties. Recently,
organic chain molecules (such as polydiacetilene) which are different realizations of one dimensional electronic systems, have been shown also to have interesting optical nonlinearities. Both the development and study of optical and electro-optical devices, as well as experimental and theoretical investigations of the underlying optical nonlinearities, are contained in this book.

Ultrafast Dynamics of Quantum Systems This Briefs volume describes the properties and structure of elementary excitations in isotope low-dimensional structures. Without assuming prior knowledge of quantum physics, the present book provides the basic knowledge needed to understand the recent developments in the sub-disciplines of nanoscience isotopetronics, novel device concepts and materials for nanotechnology. It is the first and comprehensive interdisciplinary account of the newly developed scientific discipline isotopetronics.

Advances in Condensed-Matter and Materials Physics The theory of electronic states in the traditionally solid state physics is essentially a theory of electronic states in crystals of infinite size. However, any real crystal always has a finite size. This book presents an analytical theory on the electronic states in ideal low-dimensional systems and finite crystals recently developed by the author based on a differential equation theory approach. It gives some exact and general fundamental understandings on the electronic states in ideal low-dimensional systems and finite crystals and provides new insights on some fundamental problems in low-dimensional systems such as the surface states, quantum confinement effects etc, some of them are quite different from what are traditionally believed in the solid state physics community.

Solid State Properties This volume comprises the proceedings of the NATO Advanced Research Workshop on the Science and Engineering of 1- and 0-dimensional semiconductors held at the University of Cadiz from 29th March to 1st April 1989, under the auspices of the NATO International Scientific Exchange Program. There is a wealth of scientific activity on the properties of two-dimensional semiconductors arising largely from the ease with which such structures can now be grown by precision epitaxy techniques or created by inversion at the silicon-silicon dioxide interface. Only recently, however, has there burgeoned an interest in the properties of structures in which carriers are further confined with only one or, in the extreme, zero degrees of freedom. This workshop was one of the first meetings to concentrate almost exclusively on this subject: that the attendance of some forty researchers only represented the community of researchers in the field testifies to its rapid expansion, which has arisen from the increasing availability of technologies for fabricating structures with small enough (sub - 0.1/tm) dimensions. Part I of this volume is a short section on important topics in nanofabrication. It should not be assumed from the brevity of this section that there is little new to be said on this issue: rather that to have done justice to it would have diverted attention from the main purpose of the meeting which was to highlight experimental and theoretical research on the structures themselves.

Semiconductor Optics 1 This invaluable textbook presents the basic elements needed to understand and research into semiconductor physics. It deals with elementary excitations in bulk and low-dimensional semiconductors, including quantum wells, quantum wires and quantum dots. The basic principles underlying optical nonlinearities are developed, including excitonic and many-body plasma effects. Fundamentals of optical bistability, semiconductor lasers, femtosecond excitation, the optical Stark effect, the semiconductor photon echo, magneto-optic effects, as well as bulk and quantum-confined Franz-Keldysh effects, are covered. The material is presented in sufficient detail for graduate students and researchers with a general background in quantum mechanics. This fifth edition includes an additional chapter on 'Quantum Optical Effects' where the theory of quantum optical effects in semiconductors is detailed. Besides deriving the 'semiconductor luminescence equations' and the expression for the stationary luminescence spectrum, the results are presented to show the importance of Coulombic effects on the semiconductor luminescence and to elucidate the role of excitonic populations.

Optical Properties of III-V Semiconductors Based on a NATO Advanced Summer Institute, this volume discusses physical models, mathematical formalisms, experimental techniques, and applications for ultrafast dynamics of quantum systems. These systems are used in laser optics, spectroscopy, and utilize monochromaticity, spectral brightness, coherence, power density, and tunability of laser sources.